EMS11HHA-133.000M



- Nominal Frequency

133.000MHz

Spread Spectrum

±0.25% Center Spread

EMS11 H H A -133.000M

Frequency Tolerance/Stability —

±50ppm Maximum over -40°C to +85°C
Output Control Function

Tri-State (Disabled Output High Impedance)

ELECTRICAL SPECIFICATIONS

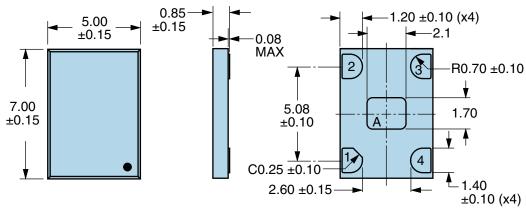
133.000MHz **Nominal Frequency Frequency Tolerance/Stability** ±50ppm Maximum over -40°C to +85°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration) Aging at 25°C ±1ppm Maximum First Year Supply Voltage 1.8Vdc ±5% Maximum Supply Voltage -0.5Vdc to +1.98Vdc 35mA Maximum (Unloaded; Nominal Vdd) Input Current Output Voltage Logic High (Voh) 90% of Vdd Minimum (IOH=-8mA) **Output Voltage Logic Low (Vol)** 10% of Vdd Maximum (IOL=+8mA) **Rise/Fall Time** 2nSec Maximum (Measured from 20% to 80% of waveform) **Duty Cycle** 50 ±10(%) (Measured at 50% of waveform) Load Drive Capability 15pF Maximum **Output Logic Type** CMOS **Output Control Function** Tri-State (Disabled Output High Impedance) Tri-State Input Voltage (Vih and Vil) 70% of Vdd Minimum or No Connection to Enable Output, 30% of Vdd Maximum to Disable Output 20mA Maximum (Disabled Output: High Impedance) (Pad 1=Ground) **Disable Current** Spread Spectrum ±0.25% Center Spread **Modulation Frequency** 30kHz Minimum, 32kHz Typical, 35kHz Maximum **Period Jitter** 90pSec Maximum (Cycle to Cycle; Spread Spectrum-On; Fo=133.333M, Vdd=1.8Vdc) Start Up Time 10mSec Maximum Storage Temperature Range -55°C to +125°C

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

ESD Susceptibility	MIL-STD-883, Method 3015, Class 2, HBM 2000V
Flammability	UL94-V0
Mechanical Shock	MIL-STD-883, Method 2002, Condition G, 30,000G
Moisture Resistance	MIL-STD-883, Method 1004
Moisture Sensitivity Level	J-STD-020, MSL 1
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003 (Four I/O Pads on bottom of package only)
Temperature Cycling	MIL-STD-883, Method 1010, Condition B
Thermal Shock	MIL-STD-883, Method 1011, Condition B
Vibration	MIL-STD-883, Method 2007, Condition A, 20G

EMS11HHA-133.000M

MECHANICAL DIMENSIONS (all dimensions in millimeters)

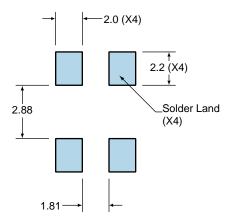


PIN	CONNECTION
1	Tri-State (High Impedance)
2	Ground
3	Output
4	Supply Voltage
LINE	MARKING
1	XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Lot Code

Note A: Center paddle is connected internally to oscillator ground (Pad 2).

Suggested Solder Pad Layout

All Dimensions in Millimeters

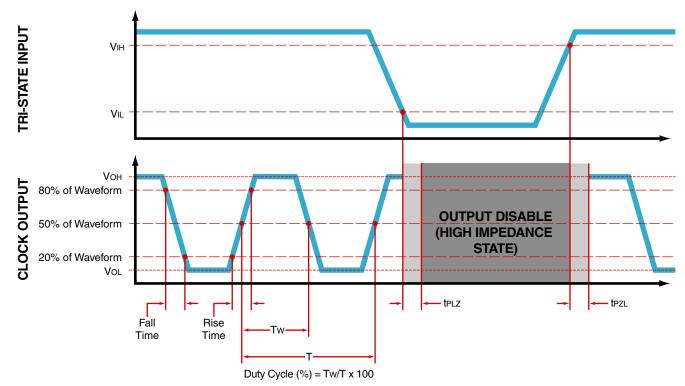


All Tolerances are ±0.1

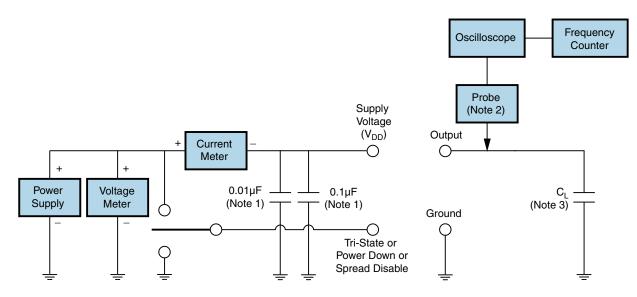
EMS11HHA-133.000M



OUTPUT WAVEFORM & TIMING DIAGRAM



Test Circuit for CMOS Output



Note 1: An external 0.1μ F low frequency tantalum bypass capacitor in parallel with a 0.01μ F high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value C_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

EMS11HHA-133.000M

T _s MAX to T _L (Ramp-up Rate)	3°C/second Maximum
Preheat	4700
 Temperature Minimum (T_s MIN) 	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _s MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T _L)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t _p)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods

EMS11HHA-133.000M



Low Temperature Infrared/Convection 240°C

T _s MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T⊾ to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (t_p)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.